Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	6	("4803664" | "5675160" | "5712817" | "5936881" | "6016268" | "6121079").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/11 10:14
S1	9	"365"/$.ccls. and (non-volatile or non$volatile or nonvolatile or flash) same DRAM same power-on same power-off	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 14:28
S2	20	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and (power-on with perform$3) and (power-off with stor$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 10:56
S3	2	("5960085" | "6119228").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/27 14:27
S4	11	(non-volatile or non$volatile or nonvolatile or flash) same DRAM same power-on same power-off	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 14:29
S5	15705	(non-volatile or non$volatile or nonvolatile or flash) same DRAM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 14:30
S6	2009	(non-volatile or non$volatile or nonvolatile or flash) same (DRAM with cell$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 14:30
S7	979	S6 and (cell with capacitor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 14:30
S8	232	S7 and (transistor with (float$3 with gate))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 14:31
S9	2	S8 and ((power-on or (power adj on)) with perform$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 14:40

S10	20	S8 and (power-on or (power adj on))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/27 14:41
S11	2	"4,055837".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/28 08:44
S12	2	"4,175291".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/28 08:45
S13	2	"3,916390".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/28 08:45
S14	2	"4,471471".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/28 08:46
S15	2	"5,331188".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/28 08:48
S17	11	NVDRAM and control$$ and insulat$3 and float$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/08 18:37
S18	1	("5825064").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/28 08:53
S19	13609	(power-on or power$on or (normal$7 with mode)) and (power-off or power$off or (program with mode))	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/29 11:25
S35	4	(NVDRAM or ((non-volatile or non$volatile) with DRAM)) and (power-on or (power adj on)) and (stor$3 with float$3) and (adjust$3 with threshold)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 10:46

S36	17	("4040015" | "4279069" | "5237530" | "5339279" | "5694357" | "5828599" | "5872994" | "5937424" | "5995409" | "5999446" | "6026016" | "6131139" | "6141256" | "6181603" | "6198663" | "6201733" | "6229737").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/31 08:23
S37	16	("4890259" | "5220531" | "5241494" | "5388064" | "5623436" | "5629890" | "5638320" | "5680341" | "5687115" | "5694356" | "5745409" | "5748533" | "5748534" | "5801980" | "5818757" | "5828592").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/31 08:25
S38	29	(NVDRAM or ((non-volatile or non$volatile) with DRAM)) and (power-on or (power adj on)) and (stor$3 with float$3) and (charg$ with capacitor$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/01/31 08:31
S39	9	("5029128" | "5303182" | "5307304" | "5345415" | "5373463" | "5383150" | "5517445" | "5592646" | "5956655").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/31 08:45
S40	5	("3691535" | "4873664" | "5010518" | "5237533" | "5262986").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/31 08:50
S41	45	("4271488" | "4742549" | "4952821" | "5008799" | "5036229" | "5059815" | "5103191" | "5220531" | "5241494" | "5301097" | "5363333" | "5388064" | "5483486" | "5493249" | "5602794" | "5623436" | "5629646" | "5629890" | "5638320" | "5680341" | "5687115" | "5689201" | "5694356" | "5699312" | "5732039" | "5745409" | "5748533" | "5748534" | "5767735" | "5781473" | "5790469" | "5796293" | "5801980" | "5801987" | "5818757" | "5828592" | "5828596" | "5864247" | "5977803" | "5999040" | "6031399" | "6184726" | "6185119" | "6208542" | "6370075").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/31 08:58

S42	1	"5,455,786".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/31 12:11
S43	1	"5,703804".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/01/31 12:12
S44	1	(NVDRAM or ((non-volatile or non$volatile) with DRAM)) and (power-on or (power adj on)) and (stor$3 with float$3) and (float$3 with nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 10:49
S45	1	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and (power-on with perform$3) and (power-off with stor$3) and (float$3 near5 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 10:57
S46	1	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and (power-on with perform$3) and (power-off with stor$3) and (float$3 same nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 11:02
S47	15	"4,446536"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 10:59
S48	2	"4,446536".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 10:59
S49	610	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and (float$3 same nitride) and stor$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 11:04
S50	138	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and (control$4 with metal) and (float$3 same nitride) and stor$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 11:05
S51	72	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and (control$4 with metal) and (float$3 with nitride) and stor$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 11:16
S52	1	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and (control$4 with metal) same (float$3 with nitride) same stor$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 11:10

S53	33	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and (control$4 with metal) and (float$3 with nitride) and stor$3 and (ONO or (oxide-nitride-oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 11:19
S54	28	(non-volatile or non$volatile or nonvolatile or flash) and DRAM and capacit$5 and transistor$1 and (control$4 with metal) and (float$3 with nitride) and stor$3 and (ONO or (oxide-nitride-oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 11:51
S55	3	365/149,145,185.01,185.24,185, 25,185.26,185.33.ccls. and (non-volatile or non$volatile or nonvolatile or flash) and DRAM and capacit$5 and transistor$1 and (control$4 with metal) and (float$3 with nitride) and stor$3 and (ONO or (oxide-nitride-oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 12:09
S56	9	"365"/$.ccls. and (non-volatile or non$volatile or nonvolatile or flash) and DRAM and capacit$5 and transistor$1 and (control$4 with metal) and (float$3 with nitride) and stor$3 and (ONO or (oxide-nitride-oxide))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/02 12:10
S57	4	("5100818" | "6064592" | "6151248" | "6317349").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/02 12:12
S58	4	("5060194" | "5350938" | "5483483" | "5659505").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/02 12:14
S59	6	NVDRAM and (memory adj2 cell$1) same capacitor same (transistor with float$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/08 18:43
S60	23	NVDRAM and (memory adj2 cell$1) same capacitor same transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/08 18:39
S61	22	NVDRAM and ((memory adj2 cell$1) with capacitor$1 with transistor$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/08 18:44
S62	4	("5399890" | "5436477" | "5903492" | "5976929").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/08 18:45

S63	6	("5029128" | "5307304" | "5373463" | "5383150" | "5517445" | "5592646").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/08 18:49
S64	1637	(nvdram or DRAM) and MOS same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:45
S65	840	"365"/$.ccls. and (nvdram or DRAM) and MOS same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 07:23
S66	175	"365"/$.ccls. and (nvdram or DRAM) and ((memory adj3 cell) with matrix) and MOS same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:38
S67	16	"365"/$.ccls. and (nvdram or DRAM) and ((memory adj3 cell) with matrix) and (float$3 with transistor) same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:38
S68	3	("5627392" | "5640345" | "5814850").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/11 07:43
S69	1	"6,141248".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/11 08:59
S70	46	365/149,145,185.01,185.24,185, 25,185.26,185.33.ccls. and (nvdram or DRAM) and ((memory adj3 cell) with matrix) and MOS same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:38
S71	11	365/149,145,185.01,185.24,185, 25,185.26,185.33.ccls. and (nvdram or DRAM) and ((memory adj3 cell) with matrix) and (float$3 with transistor) same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:49
S72	3	("5627392" | "5640345" | "5814850").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/11 08:40
S73	243	365/149,145,185.01,185.24,185, 25,185.26,185.33.ccls. and (nvdram or DRAM) and MOS same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:41

S74	64	("20010028078" | "20010030338" | "20010032997" | "20010053096" | "20020098639" | "20020126536" | "20030001191" | "20030155604" | "20030205754" | "4826780" | "4970689" | "4999811" | "5017504" | "5021355" | "5042011" | "5066607" | "5122986" | "5220530" | "5280205" | "5308783" | "5378914" | "5381302" | "5385853" | "5414288" | "5448513" | "5478772" | "5506166" | "5519236" | "5574299" | "5627785" | "5707885" | "5719409" | "5732014" | "5854500" | "5897351" | "5909618" | "5936274" | "5959327" | "5973356" | "5991225" | "6030847" | "6031263" | "6072209" | "6097065" | "6104061" | "6124729" | "6143636" | "6150687" | "6153468" | "6191448" | "6238976" | "6246083" | "6249020" | "6249460" | "6307775" | "6350635" | "6384448" | "6399979" | "6456535" | "6492233" | "6501116" | "6504201" | "6531730" | "6680864").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/11 08:43
S75	169	(nvdram or DRAM) and (float$3 with transistor) same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:49
S76	12	365/149,145,185.01,185.24,185.25,185.26,185.33.ccls. and (nvdram or DRAM) and ((memory adj3 cell) with matrix) and (float$3 with transistor) same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:48
S77	11	365/149,145,185.01,185.24,185,25,185.26,185.33,185.08.ccls. and (nvdram or DRAM) and ((memory adj3 cell) with matrix) and (float$3 with transistor) same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:53
S78	55	365/149,145,185.01,185.24,185,25,185.26,185.33,185.08.ccls. and (nvdram or DRAM) and (float$3 with transistor) same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:50

S79.	56	365/149,145,185.01,185.24,185.25,185.26,185.33,185.08.ccls. and (nvdram or DRAM) and (float$3 with transistor) same capacitor same voltage	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/11 08:50
S80	35	("3387286" | "4051354" | "4313106" | "4471240" | "5105388" | "5327380" | "5406524" | "5455791" | "5464785" | "5555206" | "5559449" | "5579259" | "5608670" | "5646428" | "5671178" | "5706227" | "5740104" | "5754477" | "5790455" | "5801401" | "5811865" | "5852306" | "5936274" | "5959896" | "5973356" | "5991225" | "6049477" | "6100559" | "6124729" | "6137725" | "6222224" | "6246089" | "6249460" | "6351428").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/11 08:50
S81	1	"5418739".PN.	USPAT; USOCR	OR	OFF	2005/06/11 08:52
S82	1	"6,009,011".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/11 09:00